NSN 5961-01-131-8020

Transistor - Page 1 of 1

View Online at https://aerobasegroup.com/nsn/5961-01-131-8020

Inclosure Material:

Metal

Overall Length:

Between 1.553 inches and 1.573 inches

Overall Height:

Between 0.670 inches and 0.920 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

15.00 amperes source cutoff current

Power Rating Per Characteristic:

115.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0

